Infineon Technologies for Hydrogen based Power Conversion/generation/

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Tim McDonald, Sr. Director, Applications and Marketing December 2, 2021





The four key trends to drive semiconductor growth



Wide band-gap (WBG) technologies complement silicon to meet the most demanding requirements

Infineon develops technologies that are linked to megatrends along the energy conversion chain, including Hydrogen









Si, SiC, and GaN Technologies cover a wide range of power/voltage /frequency



Silicon (Si)

- Targeting voltages ranging from 25 V – 1.7 kV
- > The mainstream technology
- > Suitable from low to high power

Silicon carbide (SiC)

- Targeting voltages ranging from 650 V – 3.3 kV
- High power from moderate to high switching frequency

Gallium nitride (GaN)

- Targeting voltages ranging from 80 V – 650 V
- Medium power at highest switching frequency



600 V / 650 V segment

CoolMOS[™], CoolSiC[™] and CoolGaN[™] coexists, addressing applications such as: Datacenter and telecom SMPS, Industrial SMPS, solar inverters, energy storage, UPS, battery formation, EV charging, motor drives plus automotive applications like OBC (on-board charger)

There are several "loads" and power levels for fuel cell electricity generation





From https://www.greencarcongress.com/2020/07/20200720-bloom.html

Power Converter is key link between Fuel Cell and useful work in vehicle or output to grid





Cost of fuel cell for a given application can be lowered by use of WBG devices since higher useful work results due to higher conversion efficiency



Part of your life. Part of tomorrow.